TOSHIBA Transistor Silicon PNP Triple Diffused Type

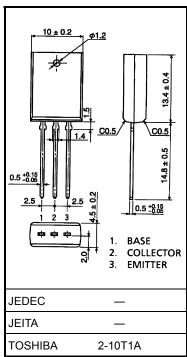
# 2SB1640

#### Audio Frequency Power Amplifier

- Low saturation voltage: VCE (sat) = -1.5 V (max) (IC = -2 A, IB = -0.2 A)
- Collector metal (fin) is covered with mold region.
- Complementary to 2SD2525

#### Maximum Ratings (Ta = 25°C)

| Characteristics             |       | Symbol           | Rating     | Unit |  |
|-----------------------------|-------|------------------|------------|------|--|
| Collector-base voltage      |       | V <sub>CBO</sub> | -60        | V    |  |
| Collector-emitter voltage   |       | V <sub>CEO</sub> | -60        | V    |  |
| Emitter-base voltage        |       | V <sub>EBO</sub> | -7         | V    |  |
| Collector current           | DC    | Ι <sub>C</sub>   | -3         | A    |  |
|                             | Pulse | I <sub>CP</sub>  | -6         |      |  |
| Base current                |       | Ι <sub>Β</sub>   | -0.5       | А    |  |
| Collector power dissipation |       | P <sub>C</sub>   | 1.8        | W    |  |
| Junction temperature        |       | Тј               | 150        | °C   |  |
| Storage temperature range   |       | T <sub>stg</sub> | -55 to 150 | °C   |  |

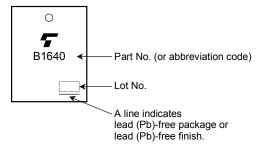


Weight: 1.5 g (typ.)

### **Electrical Characteristics (Ta = 25°C)**

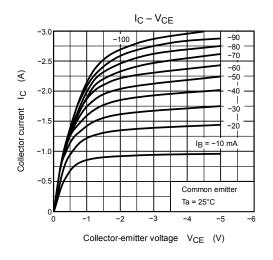
| Characteristics                      | Symbol                | Test Condition                                  | Min | Тур.  | Max  | Unit |
|--------------------------------------|-----------------------|---|-----|-------|------|------|
| Collector cut-off current            | I <sub>CBO</sub>      | $V_{CB} = -60 \text{ V}, I_E = 0$               | —   | _     | -10  | μA   |
| Emitter cut-off current              | I <sub>EBO</sub>      | $V_{EB} = -7 V, I_C = 0$                        | _   | —     | -10  | μA   |
| Collector-emitter breakdown voltage  | V (BR) CEO            | I <sub>C</sub> = -50 mA, I <sub>B</sub> = 0     | -60 | _     | _    | V    |
| DC current gain                      | h <sub>FE (1)</sub>   | $V_{CE}$ = -5 V, I <sub>C</sub> = -0.5 A        | 100 | —     | 320  |      |
|                                      | h <sub>FE (2)</sub>   | $V_{CE} = -5 V, I_C = -2 A$                     | 15  | _     | _    |      |
| Collector-emitter saturation voltage | V <sub>CE (sat)</sub> | I <sub>C</sub> = -2 A, I <sub>B</sub> = -0.2 A  | _   | -0.1  | -1.5 | V    |
| Base-emitter voltage                 | V <sub>BE</sub>       | $V_{CE} = -5 V, I_C = -0.5 A$                   | _   | -0.75 | -1.0 | V    |
| Transition frequency                 | f <sub>T</sub>        | $V_{CE}$ = -5 V, I <sub>C</sub> = -0.5 A        |     | 9     | _    | MHz  |
| Collector output capacitance         | C <sub>ob</sub>       | $V_{CB}$ = -10 V, I <sub>E</sub> = 0, f = 1 MHz | _   | 50    | _    | pF   |

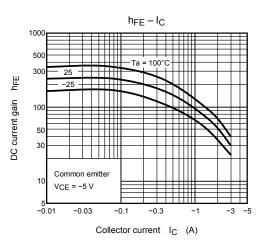
## Marking

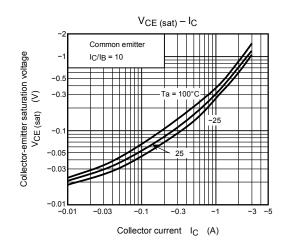


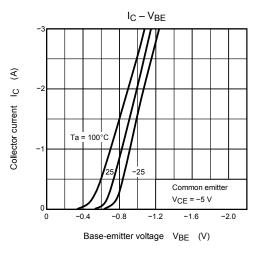
Unit: mm

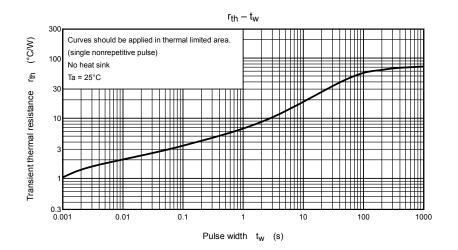
# **TOSHIBA**

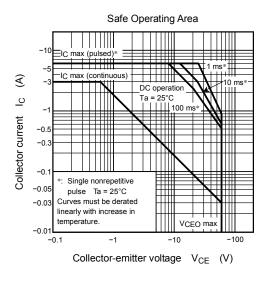


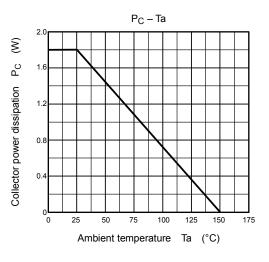












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